



#### SESOTXXC

# Dual Transient Voltage Suppressors Array for ESD Protection

Revision:C

## **General Description**

The SESOTXXC is a dual monolithic voltage suppressor designed to protect components which are connected to data and transmission lines against ESD. It clamps the voltage just above the logic level supply for positive transients and to a diode drop below ground for negative transients. It can also work as bidirectional suppressor by connecting only pin1 and 2.

## **Applications**

- Computers
- Printers
- Communication systems

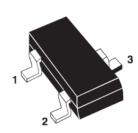
#### **Features**

- 2 Unidirectional Transil functions
- Low leakage current: I<sub>R</sub> max< 20 μA at V<sub>RM</sub>
- 300W peak pulse power(8/20µs)
- Transient protection for data lines as per

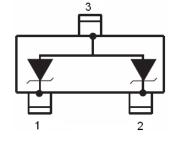
# Complies with the following standards IEC61000-4-2

Level 4 15 kV (air discharge) 8 kV(contact discharge) MIL STD 883E - Method 3015-7 Class 3 25 kV HBM (Human Body Model)

## **Functional diagram**



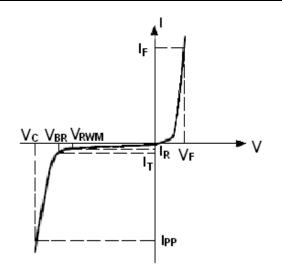
**SOT-23** 



Absolute Ratings (T <sub>amb</sub> =25°C)						
Symbol	Parameter	Value	Units			
$P_{PP}$	Peak Pulse Power (tp = 8/20µs)	350	W			
$T_L$	Maximum lead temperature for soldering during 10s	260	°C			
T <sub>stg</sub>	Storage Temperature Range	-55 to +155	°C			
$T_{op}$	Operating Temperature Range	-40 to +125	°C			
T <sub>j</sub>	Maximum junction temperature	150	°C			
V <sub>PP</sub>	Electrostatic discharge IEC61000-4-2 air discharge IEC61000-4-2 contact discharge	15 8	kV			

# **Electrical Parameter**

Symbol	Parameter					
I <sub>PP</sub>	Maximum Reverse Peak Pulse Current					
V <sub>C</sub>	Clamping Voltage @ I <sub>PP</sub>					
$V_{RWM}$	Working Peak Reverse Voltage					
I <sub>R</sub>	Maximum Reverse Leakage Current @ V <sub>RWM</sub>					
I <sub>T</sub>	Test Current					
$V_{BR}$	Breakdown Voltage @ I <sub>T</sub>					



## **Electrical Characteristics**

	<b>V</b> <sub>BR</sub>						С
Part Numbers	Min.	Тур.	Max.	Ι <sub>τ</sub>	$V_{RWM}$	I <sub>R</sub>	Typ. 0v bias
	V	V	V	mA	V	μA	pF
SESOT04C	5.0	5.6	6.2	1	4.0	1	30
SESOT05C	6.0	6.7	7.4	1	5.0	1	30
SESOT12C	13.3	14.0	14.7	1	12.0	1	25
SESOT15C	16.7	17.4	18.1	1	15.0	1	25
SESOT24C	26.7	28.2	29.6	1	24.0	1	20

<sup>1).8/20</sup> waveform used. (see fig2.)

## **Typical Characteristics**

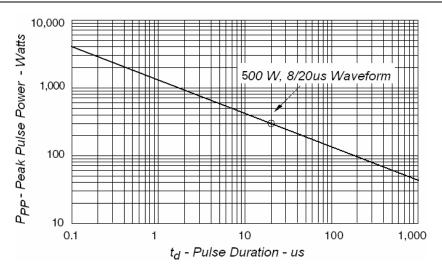
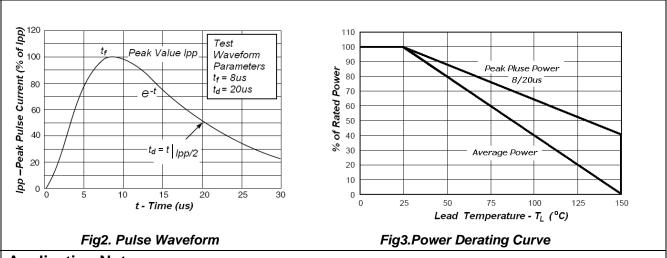


Fig1. Peak Pulse Power VS Pulse Time

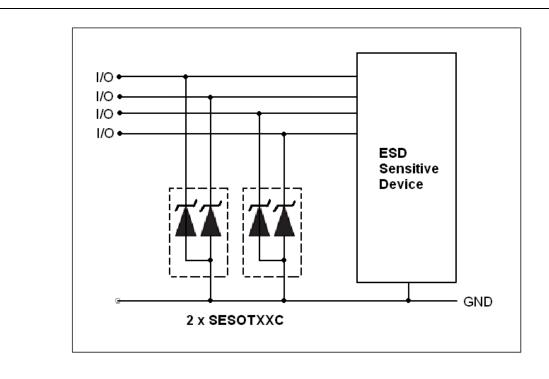


### **Application Note**

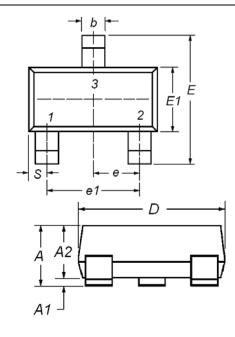
Electrostatic discharge (ESD) is a major cause of failure in electronic systems. Transient Voltage Suppressors (TVS) are an ideal choice for ESD protection. They are capable of clamping the incoming transient to a low enough level such that damage to the protected semiconductor is prevented.

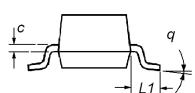
Surface mount TVS arrays offer the best choice for minimal lead inductance. They serve as parallel protection elements, connected between the signal line to ground. As the transient rises above the operating voltage of the device, the TVS array becomes a low impedance path diverting the transient current to ground. The SESOTxxC array is the ideal board evel protection of ESD sensitive semiconductor components.

The tiny SOT-23 package allows design flexibility in the design of high density boards where the space saving is at a premium. This enables to shorten the routing and contributes to hardening against ESD.



### **SOT-23 mechanical data**





Dim	Millimeters			
Dilli	Min	TYP	Max	
Α	1.00	1.20	1.40	
A1	0	0.05	0.10	
A2	1.00	1.15	1.30	
b	0.35	0.40	0.50	
С	0.10	0.15	0.20	
D	2.70	2.90	3.10	
Е	2.40	2.60	2.80	
E1	1.40	1.50	1.60	
е	0.85	1.00	1.15	
e1	1.80	1.90	2.00	
L1	0.40			
q	0°	5°	10°	
S	0.45	0.50	0.55	

The SINO-IC logo is a registered trademark of ShangHai Sino-IC Microelectronics Co., Ltd.
© 2005 SINO-IC – Printed in China – All rights reserved.

### SHANGHAI SINO-IC MICROELECTRONICS CO., LTD

Add: Building 3, Room 3401-03, No.200 Zhangheng Road, ZhangJiang Hi-Tech Park, Pudong,

Shanghai 201203, China

**Phone:** +86-21-33932402 33932403 33932405 33933508 33933608

Fax: +86-21-33932401

Email: webmaster@sino-ic.com
Website: http://www.sino-ic.com